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View Online at https://aerobasegroup.com/nsn/5961-01-319-1727 **Inclosure Material:** Metal **Overall Length:** 27.6 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 8.5 millimeters **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 0.20 amperes source cutoff current **Transfer Ratio:** 70.0 static forward current transfer ratio, common-emitter and 300.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Base metallization gold **Precious Material:** Gold **Thread Series Designator: Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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